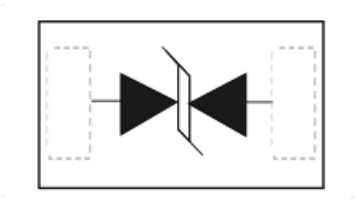
Description

The LESD8LH5.0CT5G is designed to protect voltage sensitive components that require ultra−low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed and antenna line applications.



Features

- Ultra Low Capacitance 3 pF
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.039″ x 0.024″ (1.00 mm x 0.60mm)
- Low Body Height: 0.020 ″(0.5 mm)
- Stand−off Voltage: 5 V
- Low Leakage
- Response Time is Typically < 1.0 ns
- IEC61000−4−2 Level 4 ESD Protection
- This is a Pb−Free Device

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic Epoxy Meets UL 94 V−0
LEAD FINISH: 100% Matte Sn (Tin)
QUALIFIED MAX REFLOW TEMPERATURE:260°C
Device Meets MSL 1 Requirements

MAXIMUM RATINGS

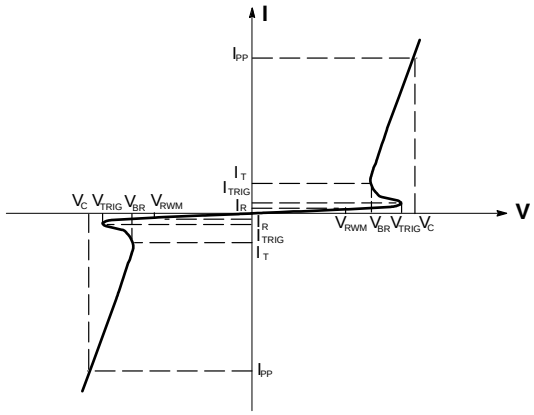
Rating	Symbol	Value	Unit
IEC61000−4−2 (ESD) Contact Air		±10 ±15	kV
Total Power Dissipation on FR−5 Board (Note 1) @ T_A = 25 °C	P_D	150	mW
Storage Temperature Range	T_{stg}	−55 to +150	°C
Junction Temperature Range	T_J	−55 to +125	°C
Lead Solder Temperature − Maximum (10 Second Duration)	T_L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR−5 = 1.0 x 0.75 x 0.62 in.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse standoff voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
V_{TRIG}	Reverse trigger voltage
I_{TRIG}	Reverse trigger current



Bi−Directional TVS

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Device	V_{RWM} (V)	I_R (uA) @ V_{RWM}	V_{BR} (V) @ I_T = 1mA (Note 2)	C (pF)		V_C (V) @ I_{PP} = 3.5 A (Note 3)	I_{PP} (A) t_p=8/20μs	P_{PP} (W)	V_C
	Max	Max	Min	Typ	Max	Max	Max	Max	Per IEC61000−4−2 (Note4)
LESD8LH5.0CT5G	5.0	1	5.5	2.7	3.5	11.5	3.5	40	Figures 1 and 2 See Below

2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.
3. Surge current waveform per Figure 4.
4. For test procedure see Figures 3.

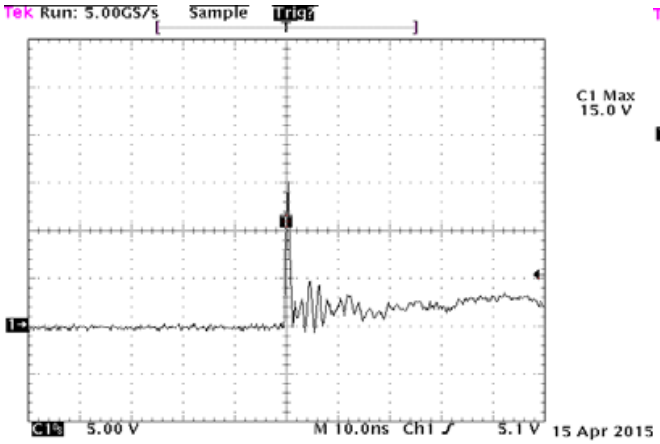


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000−4−2

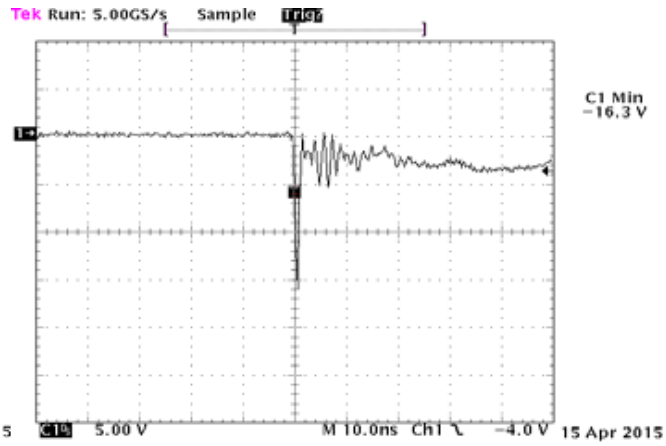


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000−4−2

IEC 61000−4−2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

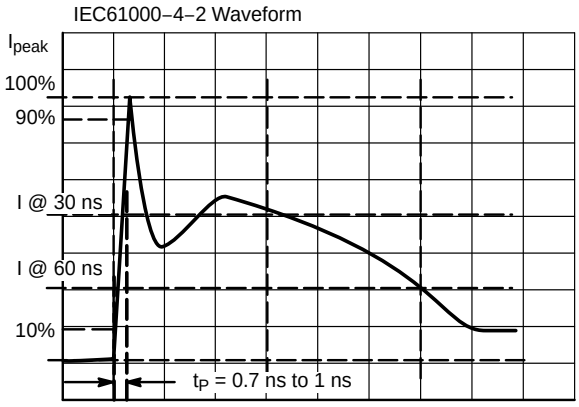
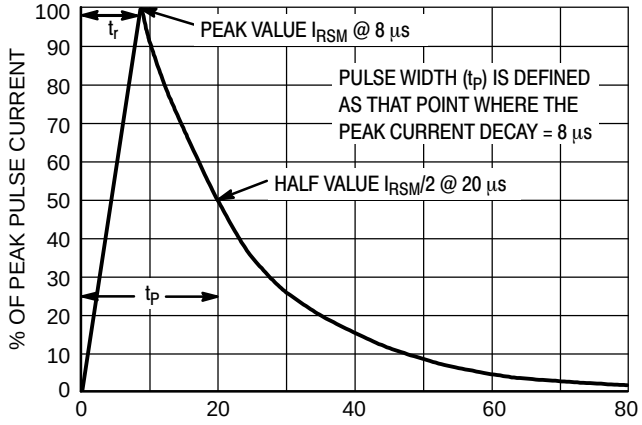
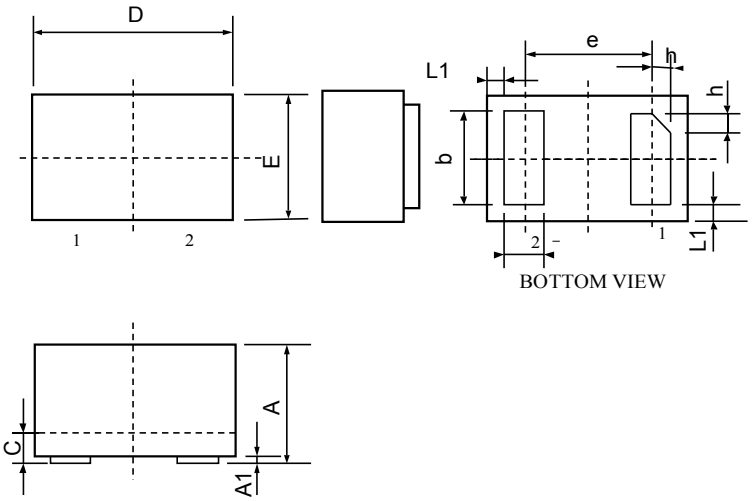


Figure 3. IEC61000−4−2 Spec

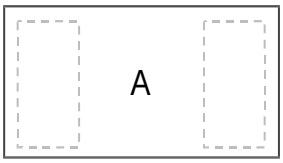


Outline Drawing – SOD-882



SYMBOL	MILIMETER		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.50	0.55
C	0.12	0.15	0.18
D	0.95	1.00	1.05
e	0.65BSC		
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.05REF		
h	0.07	0.12	0.17

Marking



Ordering information

Order code	Package	Baseqt	Deliverymode
UMW LESD8LH5.0CT5G	SOD-882	10000	Tape and reel

Unikeyic Electronics

Global Electronic Components Distributor

Click to view pricing, inventory, delivery, and lifecycle information:

UMW:

LMV612MAX PESD24VL1BA 78M08 BAT54 LM2903DR P4SMA6.8CA XC6206P362MR BAS21S SMBJ188CA TSV611ILT HT7330-A HT7550S SN74LV1T08DCKR SN74LVC2G07DBVR TMP75AIDGKR LM2576HVS-ADJ TSV6291ILT FQD17P06TM SN74AHCT1G86DBVR SN74LVC1G126DRYR FDD4685 LMV722IDR SN74LVC1G32DRYR 1N60L AMS1117-1.5 LM293DR LM317MDT SI2318A XC6206P302PR LM2596HVS-12